

	<h2>SI3465DV-T1-E3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI3465DV-T1-E3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 20V 3A 6-TSOP</p> <p><b>Datenblätter:</b>  <a href="#">SI3465DV-T1-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 95725 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI3465DV-T1-E3</a>
Hersteller	<a href="#">Vishay / Siliconix</a>
Beschreibung	MOSFET P-CH 20V 3A 6-TSOP
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	95725 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	1.14W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3A (Ta)
Rds On (Max) @ Id, Vgs	80 mOhm @ 4A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	5.5nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)

















































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Sie können auch interessiert sein:

 <p><b>SI3465DV-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 20V 3A 6-TSOP</p>	 <p><b>SI3465DV-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 3A 6-TSOP</p>	 <p><b>SI3464DV-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 20V 8A 6-TSOP</p>	 <p><b>SI3467DV</b> VISHAY SI3467DV VISHAY</p>
 <p><b>SI3464DV-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 20V 8A 6-TSOP</p>	 <p><b>SI3464DV-T1-E3</b> Son Son TSOP-6</p>	 <p><b>SI3464DV</b> Vishay SI3464DV Vishay</p>	 <p><b>SI3467DV-T1-E3</b> Vishay / Siliconix MOSFET P-CH 20V 3.8A 6-TSOP</p>

### heiße Teile

Mehr

 SI3459BDV-T1-GE3	 SI3459DV-T1-E3	 SI3459DV-T1-E3	 SI3459DV-T1-GE3	 SI3460-E02-GMR
 SI3460-E03-GMR	 SI3460BDV-T1-E3	 SI3460BDV-T1-E3	 SI3460BDV-T1-GE3	 SI3460BDV-T1-GE3
 SI3460DDV	 SI3460DDV-T1-GE3	 SI3460DDV-T1-GE3	 SI3460DV	 SI3460DV-T1
 SI3460DV-T1-E3	 SI3460DV-T1-E3	 SI3460DV-T1-GE3	 SI3460DV-T1-GE3	 SI3461DV-T1-E3
 SI3461DVT1-GE3	 SI3464DV	 SI3464DV-T1-GE3	 SI3464DV-T1-GE3	 SI3465DV-T1-E3
 SI3465DV-T1-GE3	 SI3465DV-T1-GE3	 SI3467DV	 SI3467DV-T1-E3	 SI3467DV-T1-E3
 SI3467DV-T1-GE3	 SI3467DV-T1-GE3	 SI3469DV-T1	 SI3469DV-T1-E3	 SI3469DV-T1-E3
 SI3469DV-T1-GE3	 SI3469DV-T1-GE3	 SI3471DV-T1-E3	 SI3473CDV-T1-E3	 SI3473CDV-T1-E3
 SI3473CDV-T1-GE3	 SI3473CDV-T1-GE3	 SI3473DDV-T1-GE3	 SI3473DV-T1-E3	 SI3473DV-T1-E3
 SI3473DV-T1-GE3	 SI3473DV-T1-GE3	 SI3474DV-T1-GE3	 SI3474DV-T1-GE3	 SI3475DV-T1-E3

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